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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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10/804,216

03/19/2004

Toshiro Hayakawa

Q80553

6095

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EXAMINER

NGUYEN, DUNG T

ART UNIT

PAPER NUMBER

2828

SHORTENED STATUTORY PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE
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3 MONTHS

03/12/2007

PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

Office Action Summary

Application No.

10/804,216

Applicant(s)

HAYAKAWA, TOSHIRO

Examiner

Dung (Michael) T. Nguyen

Art Unit

2828

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 01 December 2006.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-3,7,9 and 10 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-3,7,9 and 10 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO/SB/08)
Paper No(s)/Mail Date _____.
- 4) ☐ Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____.
- 5) ☐ Notice of Informal Patent Application
- 6) ☐ Other: _____.

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 1-3, 7, and 9-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ramdani et al. (5633886) in view of Kawanishi et al. (2003/0138001).

With respect to claims 1 and 7, Ramdani et al. show in Fig. 1-5 a surface-emitting semiconductor laser element for emitting laser light from a surface, comprising:

a GaAs substrate 11;

semiconductor layers which are formed above said GaAs substrate in parallel to said surface, and include,

a lower mirror (10) which is realized by a semiconductor multilayer film, is formed above said GaAs substrate, and constitutes an optical resonator,

an active layer 12 formed above said lower mirror,

a current-confinement layer (14) of one of a selective-oxidation type and an ion-injection type formed above said active layer,

and an upper mirror (15) which is realized by a semiconductor multilayer film, is formed above said current-confinement layer, and constitutes said optical resonator;

and a pair of electrodes (col.4, 1.37-39) which inject current into said active layer;

wherein said active layer includes, a quantum well 21 (GaAsP) having a first forbidden band width, and sublayers (barriers 25-26) arranged adjacent to said quantum well and made of InGaP which has a second forbidden band width greater than said first forbidden band width (col.3, 1.58-61);

and said lower mirror and said upper mirror are made of AlGaAs.

Ramdani et al. fail to disclose the quantum well made of InGaAsP.

Kawanishi et al. teach the quantum well made of alternate materials of InGaAsP and GaAsP (para.0075).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to provide Ramdani et al. what is taught by Kawanishi et al. to interchange different materials for the quantum well.

With respect to claims 2 and 3, Ramdani et al. disclose each of said quantum well and said sublayers has such a composition so as to lattice-match with GaAs and wherein said quantum well has such a composition so as to cause compressive strain with respect to GaAs, and each of said sublayers has such a composition so as to lattice-match with GaAs (col.3, 1.46-67).

With respect to claim 9-10, Ramdani et al. disclose the wavelength of 780nm (col.3, 1.15-16).

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Communication Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung (Michael) T Nguyen whose telephone number is (571) 272-1949. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Min Harvey can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3329.



Michael Dung Nguyen

2/21/07